

## Quantum Optics with Semiconductor Double Quantum Dots

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Cavity-coupled double quantum dots (DQDs) allow the investigation of non-equilibrium physics in strongly-driven quantum systems. I will describe recent experiments that examine light-matter interactions at the single particle level. The application of a source-drain bias across a DQD results in single electron tunneling and population inversion. The interdot tunneling process generates photons and leads to above-threshold maser action.<sup>1</sup> We also demonstrate a novel Sisyphus light source, where one and the same electron is repeatedly pushed uphill in energy, only to relax back to the ground state by emitting a photon.<sup>2</sup> Working towards coherent spin-photon interactions, we have recently demonstrated strong coupling of a single electron in silicon to a single microwave frequency photon.<sup>3</sup>

<sup>1</sup>Y.-Y. Liu, J. Stehlik, C. Eichler, M. J. Gullans, J. M. Taylor, J. R. Petta, *Science* **347**, 285 (2015).

<sup>2</sup>J. Stehlik, Y.-Y. Liu, C. Eichler, T. R. Hartke, X. Mi, M. J. Gullans, J. M. Taylor, and J. R. Petta, *Phys. Rev. X* **6**, 041027 (2016).

<sup>3</sup>X. Mi, J. V. Cady, D. M. Zajac, P. W. Deelman, J. R. Petta, *Science* **355**, 156 (2017).